

Influence of HfO₂ alloying effect on microstructure and thermal conductivity of HoTaO₄ ceramics

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Abstract: HfO₂ alloying effect has been applied to optimize thermal insulation performance of HoTaO₄ ceramics. X-ray diffraction, Raman spectroscopy, and X-ray photoelectron spectroscopy are employed to decide the crystal structure. Scanning electronic microscopy is utilized to detect the influence of HfO₂ alloying effect on microstructure. Current paper indicates that the same numbers of Ta⁵⁺ and Ho³⁺ ions of HoTaO₄ are substituted by Hf⁴⁺ cations, and it is defined as alloying effect. No crystal structural transition is introduced by HfO₂ alloying effect, and circular pores are produced in HoTaO₄. HfO₂ alloying effect is efficient in decreasing thermal conductivity of HoTaO₄ and it is contributed to the differences of ionic radius and atomic weight between Hf⁴⁺ ions and host cations (Ta⁵⁺ and Ho³⁺). The least experimental thermal conductivity is 0.8 W·K⁻¹·m⁻¹ at 900 °C, which is detected in 6 and 9 mol%-HfO₂ HoTaO₄ ceramics. The results imply that HfO₂–HoTaO₄ ceramics are promising thermal barrier coatings (TBCs) due to their extraordinary thermal insulation performance.

Keywords: thermal barrier coating (TBC); thermal conductivity; rare earth tantalates; microstructure; alloying effect; optical property

1 Introduction

Thermal barrier coating (TBC) system, which is applied in multiple gas turbines and aircraft engines, is consist of top coat ceramics, bond coat, and super-alloy substrates [1–5]. As the limit application temperature of present Ni-based alloy is less than 1200 °C, a great number of researchers are studying top coat ceramics to provide thermal insulation [6–9]. The main functions of top coat ceramics are to decrease superficial temperature of substrates and increase their application limitations. Current top coat ceramics are yttria stabilized

zirconia (YSZ), whose working temperature is less than 1200 °C. The t–m phase transition is detected in YSZ, and the unit cell volume variation caused by the transition will lead to the failure of coatings [10–12]. Nevertheless, no material is able to replace YSZ because the distinctive ferroelasticity produces excellent toughness at elevated temperature [13]. Therefore, much effort has been conducted to perfect the thermal physical performance of YSZ [12–15]. At the same time, substances exhibiting ferroelasticity are recognized as novel TBCs. Monoclinic ABO₄-type rare earth tantalates (m-RETaO₄) possess the similar ferroelasticity, which engenders extraordinary toughness [16–18]. Herein, m-RETaO₄ has been widely deliberated as candidate TBC materials. Preceding documents reveal that m-RETaO₄ displays outstanding thermal insulation performance

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($k = 1.5 \text{ W} \cdot \text{K}^{-1} \cdot \text{m}^{-1}$), and the typical microstructure has been researched [16,18]. The comprehensive properties of m-RETaO₄ are better than that of YSZ and other candidate TBCs (RE₂Zr₂O₇, RE₃TaO₇, REPO₄, and so on) [19–23]. To promote the material property of rare earth tantalates further, many methods have been tried. For example, TiO₂ and ZrO₂ alloying effects are employed to produce glass-like thermal conductivity; Al₂O₃ doping is utilized to drop thermal conductivity and enhance thermal expansion coefficients (TECs) [19,24,25]. Among various technologies, alloying effect is considered as the most effective one, as the TECs and thermal conductivity are simultaneously optimized. HoTaO₄ exhibits the best thermal radiation resistance, low Young's modulus, and thermal conductivity, as well as high TECs in the whole series of m-RETaO₄ [18]. TiO₂ and ZrO₂ alloying effects have been tried for other rare earth tantalates, as Hf, Zr, and Ti belong to the same group, HfO₂ alloying effect is tried for HoTaO₄.

In this paper, HfO₂ alloying HoTaO₄ sample had been composed through a conventional solid-state reaction. X-ray diffraction (XRD) was applied to investigate the crystal structure. Raman spectroscopy was used to appraise the molecule vibration intensity. X-ray photoelectron spectroscopy (XPS) was utilized to ascertain the chemical valence of multiple elements. Scanning electron microscopy (SEM) was employed to research the effect of HfO₂ addition on the microstructure of HoTaO₄ ceramics. Optical properties were thoroughly discussed. Thermal properties (specific heat, thermal diffusivity, and thermal conductivity) of HfO₂-HoTaO₄ were the emphasis. It is stressed that HfO₂ alloying effect is effective in optimizing thermal insulation performance of HoTaO₄ ceramics.

2 Experimental procedure

2.1 Sample preparation

Bulk $x \text{ mol\%}$ -HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) sample was composed through a solid-state reaction technique. The raw substances comprised Ho₂O₃ (net content $\geq 99.99\%$, pellet diameter $\leq 3 \mu\text{m}$), Ta₂O₅ (net content $\geq 99.99\%$, pellet diameter $\leq 5 \mu\text{m}$), HfO₂ (net content $\geq 99.99\%$, pellet diameter $\leq 5 \mu\text{m}$), and C₂OH₆ (net content $\geq 99.9\%$). Ho₂O₃, Ta₂O₅, and HfO₂ were mixed in a ball crusher (10 h, 320 r/min) within circumstance of C₂OH₆. The admixtures were kept at 105 °C for 8 h to season. The acquired substances were

suppressed into columns of 7.5 mm in radius and 2 mm in altitude. Ultimately, the columns were placed at 1700 °C for 10 h to synthesize circular $x \text{ mol\%}$ -HfO₂ HoTaO₄ specimens.

2.2 Crystal structure identification and microstructure observation

The lattice structures were distinguished through XRD (Rigaku, MiniFlex600, Japan). The 2-theta degree stretched from 10° to 70°, when the scanning velocity was 6 (°)/min and the step length was 0.02°. Herein, the testing time of each sample XRD pattern continued about 10 min. Archimedes principle was utilized to obtain the bulk density (ρ), and the porosity was computed by the relationship:

$$\phi = 1 - \rho / \rho_0 \quad (1)$$

Raman spectroscopy was more sensitive on distinguishing crystal structure variation than XRD, and it was used to research the vibration variety of unit cell and multiple chemical bonds. Confocal spectrometer (Lab RAM Aramis, Horiba-Jobin Yvon, Edison, NJ, USA) possessing a He-Ne ion laser (514.5 nm) was employed to record the Raman result. XPS was carried out within a PHI 5000 Versaprobe-II spectrometer. The specimen was burnished and was wiped to clear up any foreign pollutant. A carbon layer with C1s binding energy of 284.8 eV was coated to eliminate the experimental deviation originating from superficial charging effect.

SEM (JEOL, JSM-7001F, Tokyo, Japan) was used to survey the superficial morphology features including pores, cracks, and grain sizes, which were evidently affected by HfO₂ alloying effect. Before the observation, gold was coated on the surface to increase electrical conductivity; the resulting images with magnification of 500 and 1000 were displayed.

2.3 Property measurement

The band gap of $x \text{ mol\%}$ -HfO₂ HoTaO₄ was calculated based on reflectance R , which was measured via one UV-vis spectrophotometer (Shimadzu UV-3600plus, Japan). The reflectance curves were obtained, and the band gaps were computed according to the K-M law [26]:

$$F(R) = \frac{(1-R)^2}{2R} \quad (2)$$

where $F(R)$ exhibited a close relationship with the extinction efficiency (ϕ).

Thermal diffusivity (α) experiment was completed

in a laser flash instrument (LFA 457, Netzsch, Germany) from 25 to 900 °C. The experimental values were revised via Radiation+Pulse adjustment mold. The thermal conductivity was calculated based on α , C_p , and ρ [27]:

$$k' = \alpha C_p \rho \quad (3)$$

Specific heat (C_p) was gained by Neumann–Kopp law [30]. Pores and cracks usually produced an obvious impact on heat propagation; the thermal conductivity (k) of specimen without pores and cracks was [27]:

$$\frac{k'}{k} = 1 - \frac{4}{3}\phi \quad (4)$$

3 Results and discussion

3.1 Crystal structure

Figure 1(a) displays that XRD peaks of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) are in accordance with the patterns of PDF#24-0478, implying that each sample crystallizes in m phase, and no phase transformation has been detected. According to the ionic radius of Ho³⁺ ($r = 0.102$ nm), Ta⁵⁺ ($r = 0.064$ nm), and Hf⁴⁺ ($r = 0.083$ nm) cations, when only Ta⁵⁺ is substituted by Hf⁴⁺ or Hf⁴⁺ occurs as interstitial cation, the crystal structure will be expanded and the XRD peaks shift to left. When Ho³⁺ is substituted by Hf⁴⁺, the crystal structure will be contracted, and the XRD peaks shift to right. Figure 1(b) indicates that the 2-theta position of main XRD peaks of HfO₂–HoTaO₄ is constant; therefore, it is believed that the same numbers of Ho³⁺ and Ta⁵⁺ ions are substituted by Hf⁴⁺ cations [19,24]. A weak peak of HfO₂ is found in 9 mol%-HfO₂ HoTaO₄, which can be observed more distinctly from Fig. 1(c), proving that HfO₂ alloying content in HoTaO₄ is below 9 mol%. Figure 2(a) displays that the entire series of x mol%-HfO₂ HoTaO₄ ceramics present analogous Raman peaks; no Raman peak position shifting is discovered. The position and intensity of Raman peaks are close to the chemical bonds length and lattice vibration strength. Figures 2(b) and 2(c) imply that no palpable change of crystal structure and bonding length is introduced by HfO₂ alloying effect. Figure 3(a) displays that Hf, Ho, Ta, O, and C elements are found in 6 mol%-HfO₂ HoTaO₄ ceramics according to the binding energy. The element chemical valence can be determined based on the binding energy shown in Figs. 3(b)–3(e) [29,30]. For example, the binding energy of O²⁻ is 295.5 eV,

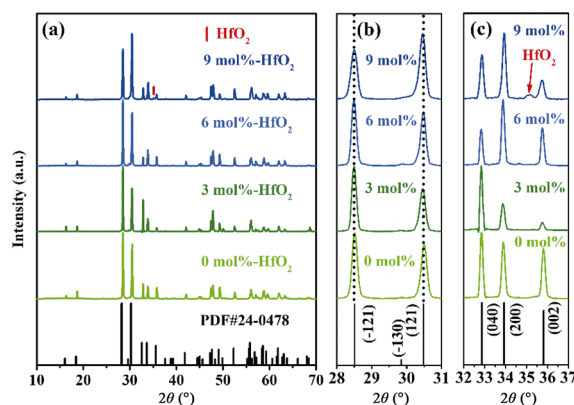


Fig. 1 Room temperature XRD patterns of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics: (a) $10^\circ \leq 2\theta \leq 70^\circ$, (b) $28^\circ \leq 2\theta \leq 31^\circ$, (c) $32^\circ \leq 2\theta \leq 37^\circ$.

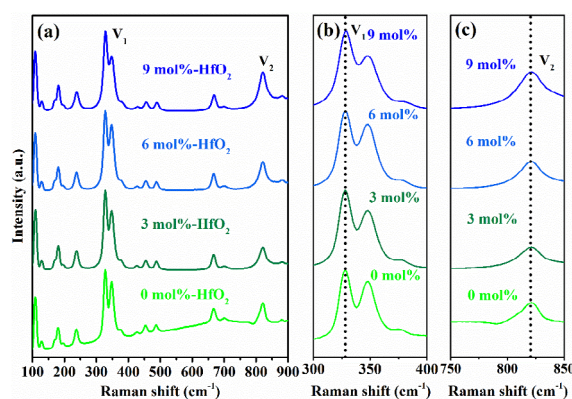


Fig. 2 Room temperature Raman spectra of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics: (a) $100\text{--}900\text{ cm}^{-1}$, (b) $300\text{--}400\text{ cm}^{-1}$, (c) $750\text{--}850\text{ cm}^{-1}$.

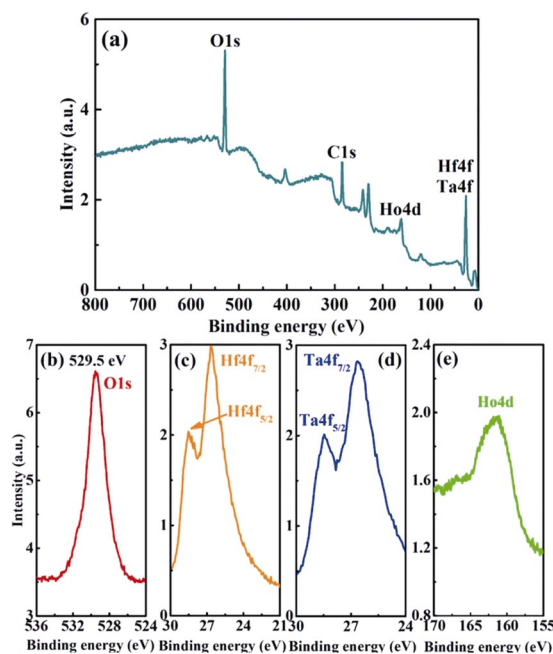


Fig. 3 XPS results of 6 mol%-HfO₂ HoTaO₄ ceramics.

indicating that O is combined with metal elements (Ta^{5+} , Hf^{4+} , Ho^{3+}) to form chemical bonds.

3.2 Microstructure

The grain size of 0 mol%-HfO₂ HoTaO₄ is small ($\leq 20 \mu\text{m}$) as displayed in Fig. 4, which is analogous to the former document [18]. In HoTaO₄, a small quantity of pore and crack is observed, and the relative density is about 95%. However, when HfO₂ is added, a large number of columnar pores are emerged as shown in Figs. 4(c)–4(h). The grain size of x mol%-HfO₂ HoTaO₄ ($x = 3, 6, 9$) is bigger than that of HoTaO₄, as it can be clearly observed from Figs. 4(d), 4(f), and 4(h). Some grains are much bigger than $20 \mu\text{m}$, and the grain boundaries are blurry, which are caused by the addition of HfO₂. The exact density and porosity of x mol%-HfO₂ HoTaO₄ are listed in Table 1. The porosity increases with increment of HfO₂ content, and the porosity of HoTaO₄ can be regulated via controlling HfO₂ content. Normally, the porosity of TBCs is about 10% [27,31,32]. Therefore, the realistic thermal and mechanical properties of HoTaO₄ coatings can be estimated by adding appropriate HfO₂ content to obtain the desirable porosity.

3.3 Optical properties

Figure 5(a) displays that the reflectance of x mol%-HfO₂ HoTaO₄ increases with increment of wavelength, and periodic decrements of reflectance are presented in some specific positions, which are caused by the Ho^{3+} internal $4f^{11}$ transition [33]. Figure 5(b) displays that the absorption decreases with increment of wavelength, which is contrary to the situation of reflectance, and the maximum absorption reaches 63% between 100

and 200 nm of wavelength range. Figure 5(c) displays that the band gaps of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6$) are similar, whereas 9 mol%-HfO₂ HoTaO₄ exhibits narrower band gap than the others, attributed to the existence of second phase HfO₂. The wide band gap of x mol%-HfO₂ HoTaO₄ proves that they are insulators and heat is carried by phonons (lattice vibration) in these solids.

3.4 Thermal conductivity

Figure 6(a) displays that the specific heat ($0.30\text{--}0.39 \text{ J}\cdot\text{K}^{-1}\cdot\text{g}^{-1}$, $25\text{--}900 \text{ }^\circ\text{C}$) of x mol%-HfO₂ HoTaO₄ increases with increment of temperature, contributed to the volume bulge and phonon excitation [17,21]. The introduction of HfO₂ makes little impact on the specific heat of HoTaO₄. Figure 6(b) displays that thermal diffusivity ($0.31\text{--}1.37 \text{ mm}^2/\text{s}$, $25\text{--}900 \text{ }^\circ\text{C}$) decreases with increment of HfO₂ quantity, and the least value is presented in 6 and 9 mol%-HfO₂ HoTaO₄. Figure 6(c) displays that thermal conductivity ($0.8\text{--}3.6 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$, $25\text{--}900 \text{ }^\circ\text{C}$) decreases with increment of temperature. The difference of thermal conductivity k' among x mol%-HfO₂ HoTaO₄ is much higher than that of the revised thermal conductivity k as shown in Figs. 6(c) and 6(d), because circular pores are effective in scattering phonons and reducing thermal conductivity. The minimum k reaches $1.3 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$ (6 mol%-HfO₂ HoTaO₄), which is much less than that of YSZ ($2.5\text{--}3.0 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$), La₂Zr₂O₇ ($1.8\text{--}3.2 \text{ W}\cdot\text{K}^{-1}\cdot\text{m}^{-1}$), and other ceramics [29,31,34,35]. The low thermal conductivity of x mol%-HfO₂ HoTaO₄ derives from the complicated crystal structure and point defects engendered by HfO₂ alloying effect. In the crystal structure of HoTaO₄, each Ta^{5+} is surrounded by four O^{2-} ions to form cage-like tetrahedron, which

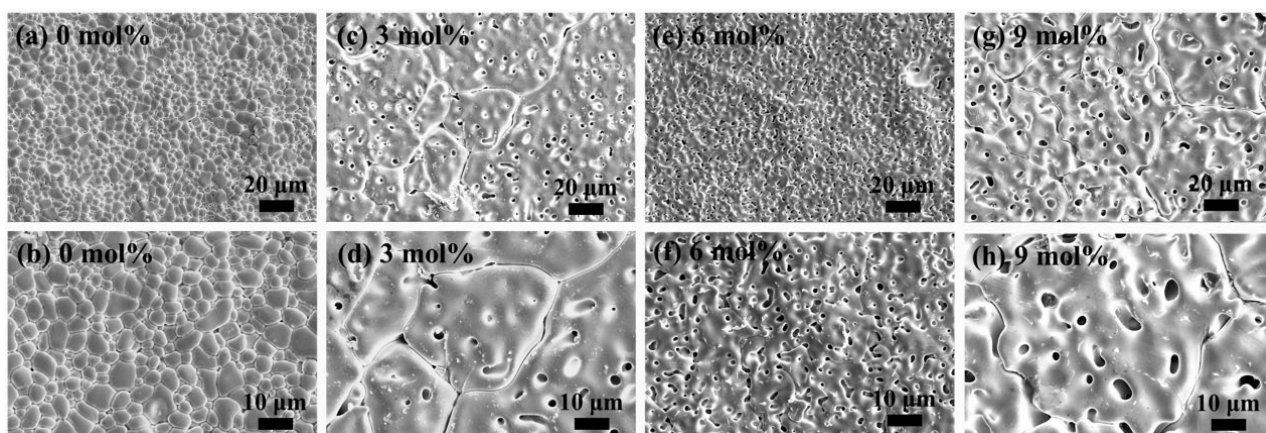


Fig. 4 Typical microstructure of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics.

Table 1 Density and porosity of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics (the theoretical density of HoTaO₄ is 9.277 g/cm³)

x (mol%)	0	3	6	9
Density (g/cm ³)	8.764	7.159	6.676	6.495
Porosity (%)	5.5	22.3	28.0	29.6

leads to violent phonons scatter. Hf⁴⁺ has longer ionic radius than Ta⁵⁺ and possesses shorter ionic radius than Ho⁴⁺. The misfits of ionic radius and atomic weight among Ta⁵⁺, Ho³⁺, and Hf⁴⁺ induce point defects and enhance phonon scattering intensity [19,36].

Figure 6(d) shows that the revised thermal conductivity k (1.3–3.7 W·K⁻¹·m⁻¹, 25–900 °C) decreases with increment of temperature. The phonon scattering intensity introduced by point defects and grain boundary is constant; the temperature dependent thermal conductivity is governed by inharmonic lattice vibration [37–40]. Raman characteristic peaks come from the particular vibration of lattice structure and chemical bonds, and the mean full wave at half maximum (FWHM) of Raman peaks can be used to assess anharmonicity of lattice vibration. Figure 7 displays that the anharmonicity of lattice vibration of x mol%-HfO₂ HoTaO₄ increases

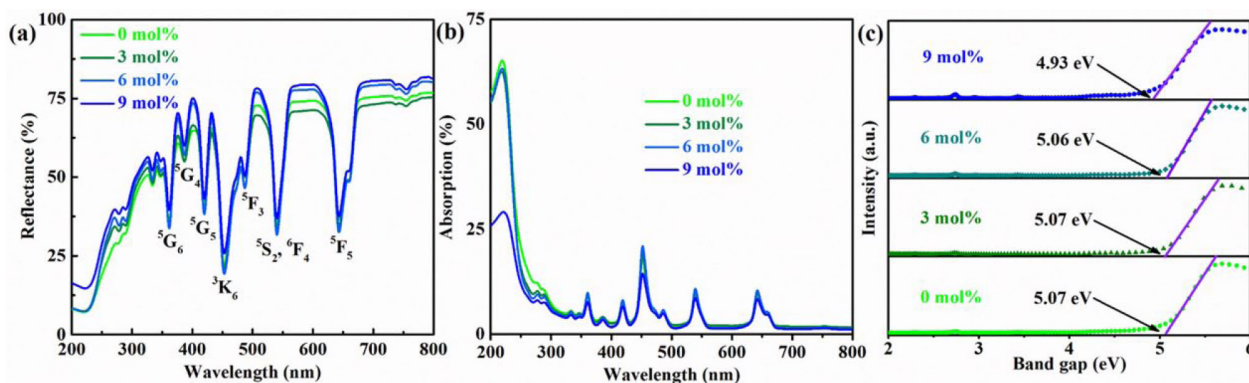


Fig. 5 Optical properties of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics: (a) reflectance, (b) absorption, (c) band gap.

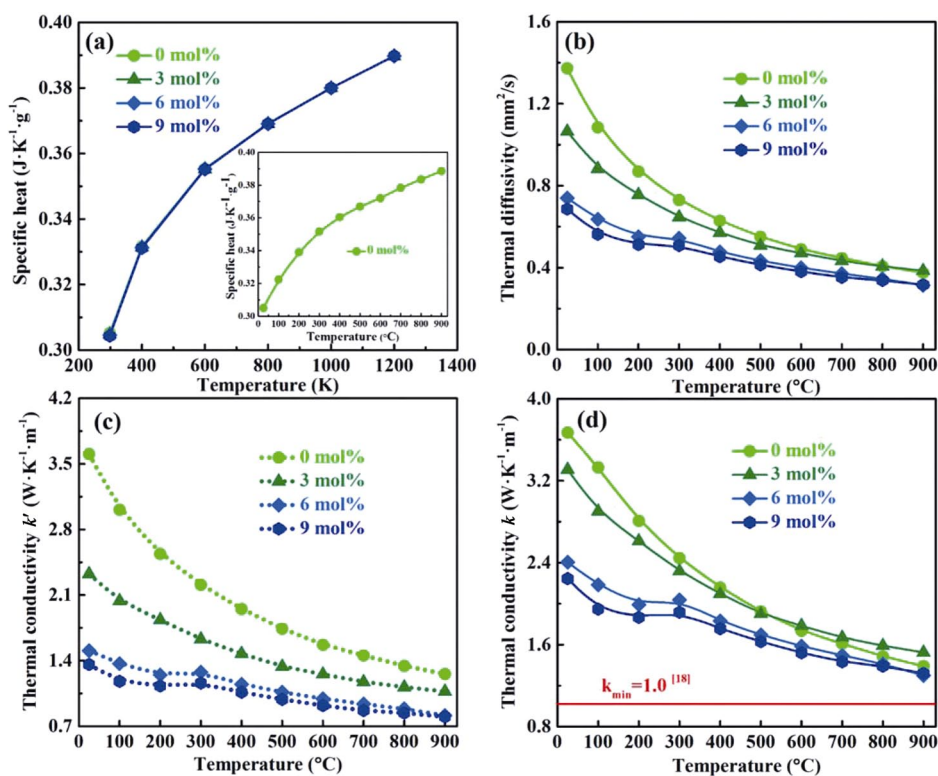


Fig. 6 Temperature dependence of thermal properties of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics: (a) specific heat, (b) thermal diffusivity, (c) thermal conductivity k' , (d) revised thermal conductivity k .

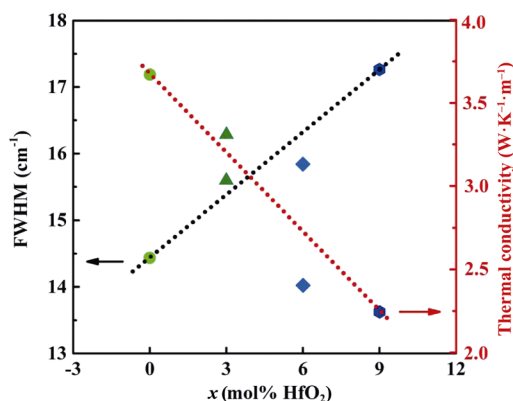


Fig. 7 Composition dependence of the revised thermal conductivity k at room temperature and the mean full wave at half maximum (FWHM) of Raman peaks of x mol%-HfO₂ HoTaO₄ ($x = 0, 3, 6, 9$) ceramics.

with increment of HfO₂ quantity, when the revised k at room temperature displays the opposite HfO₂ composition dependence. HfO₂ alloying effect enhances inharmonic lattice vibration strength and drops thermal conductivity. Figure 8(a) displays that the same amounts of Ta⁵⁺ and Ho³⁺ ions are substituted by Hf⁴⁺ cations. As the ionic radius of two Hf⁴⁺ cations is equal to the sum of one Ho³⁺ ion and one Ta⁵⁺ ion, no crystal structure expansion or shrinkage is triggered. Figure 8(b) displays that Hf⁴⁺

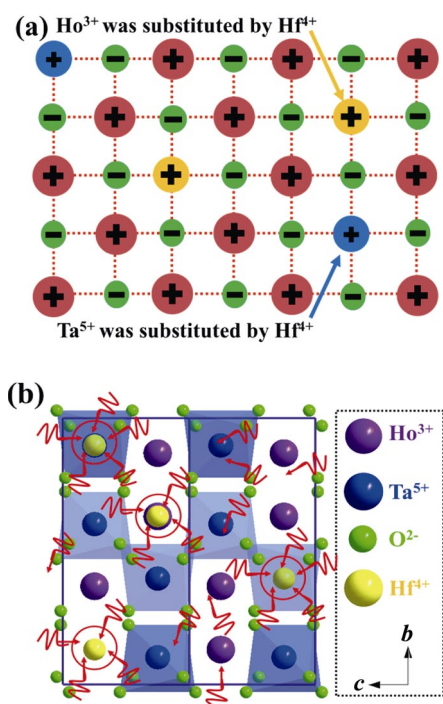


Fig. 8 Schematic drawings of 6 mol%-HfO₂ HoTaO₄ ceramics: (a) the same numbers of Ta⁵⁺ and Ho³⁺ ions are substituted by Hf⁴⁺ cations; (b) the phonon scattering principle diagram in 1×1×2 crystal structure.

cations occupying Ta⁵⁺ ionic positions are the most violent phonon scattering sources because of the cage-like tetrahedron and the distinction of ionic radius between Ta and Hf. Phonons can be scattered by Hf⁴⁺ ions to block phonon transportation and result in low thermal conductivity.

4 Conclusions

HfO₂ alloying effect is successfully employed to decrease thermal conductivity of HoTaO₄ ceramics. HfO₂ alloying content in HoTaO₄ is higher than 6 mol% and is less than 9 mol%, and no crystal structural transition is triggered. The porosity of HoTaO₄ can be regulated by controlling HfO₂ quantity. The wide band gap (~5.0 eV) proves that heat is conducted by phonons in these ceramics. HfO₂ alloying effect is effective in improving thermal insulation performance of HoTaO₄ via enhancing inharmonic lattice vibration, introducing point defects and pores. The least thermal conductivity is 0.8 W·K⁻¹·m⁻¹ (900 °C), which is much lower than that of other TBCs. Current document stresses that HfO₂ alloying HoTaO₄ ceramics are promising TBCs, contributed to the extremely low thermal conductivity.

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